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Low-Voltage CMOS Octal Buffer

With 5 V–Tolerant Inputs and Outputs (3–State, Non–Inverting)

MC74LCX244A

The MC74LCX244A is a high performance, non-inverting octal buffer operating from a 1.65 to 3.6 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5 V allows MC74LCX244A inputs to be safely driven from 5 V devices. The MC74LCX244A is suitable for memory address driving and all TTL level bus oriented transceiver applications.

Current drive capability is 24 mA at the outputs. The Output Enable (\overline{OE}) input, when HIGH, disables the output by placing them in a HIGH Z condition.

Features

- Designed for 1.65 to 3.6 V V_{CC} Operation
- 5 V Tolerant Interface Capability With 5 V TTL Logic
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When $V_{CC} = 0 V$
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10 μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 100 mA
- ESD Performance:
 - Human Body Model >2000 V
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



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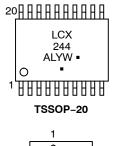
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TSSOP-20 DT SUFFIX CASE 948E

QFN20 MN SUFFIX CASE 485CB







QFN20 - 485CB

 A
 =
 Assembly Location

 L, WL
 =
 Wafer Lot

 Y, YY
 =
 Year

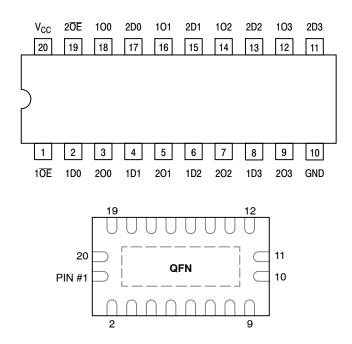
 W, WW
 =
 Work Week

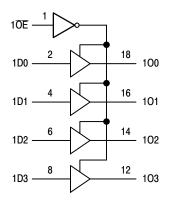
G or = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.





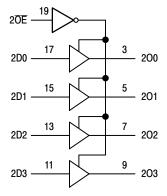


Figure 2. Logic Diagram

Figure 1. Pinouts: 20-Lead (Top View)

PIN NAMES

PINS	FUNCTION
nOE	Output Enable Inputs
1Dn, 2Dn	Data Inputs
10n, 20n	3-State Outputs

TRUTH TABLE

INP	UTS	OUTPUTS
10E 20E	1Dn 2Dn	10n, 20n
L	L	L
L	Н	н
Н	Х	Z

H = High Voltage Level

L = Low Voltage Level

Z = High Impedance State X = High or Low Voltage Level and Transitions are Acceptable

For I_{CC} reasons, DO NOT FLOAT Inputs

MAXIMUM RATINGS

Symbol	Para	meter	Value	Unit
VI	DC Input Voltage (Note 1)		-0.5 to +6.5	V
Vo	DC Output Voltage (Note 1) Ad	ctive-Mode (High or Low State)	–0.5 to V _{CC} + 0.5	V
		Tri-State Mode	-0.5 to +6.5	
	F	Power–Down Mode (V _{CC} = 0 V)	-0.5 to +6.5	
I _{IK}	DC Input Diode Current	V _{IN} < GND	-50	mA
I _{OK}	DC Output Diode Current	V _{OUT} < GND	-50	mA
Ι _Ο	DC Output Source/Sink Current		±50	mA
I _{CC}	DC Supply Current Per Supply Pin		±100	mA
I _{GND}	DC Supply Current Per Ground Pin		±100	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V_{ESD}	ESD Withstand Voltage (Note 2)	Human Body Model Charged Device Model	> 2000 N/A	V
I _{LATCHUP}	Latchup Performance (Note 3)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. I_0 absolute maximum rating must be observed.

2. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued. 3. Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

Symbol		Min	Тур	Max	Unit	
V _{CC}	Supply Voltage	Operating	1.65	3.3	3.6	V
		Data Retention Only	1.5	3.3	3.6	
VI	Digital Input Voltage		0	-	5.5	V
Vo	Output Voltage	Active Mode (High or Low State)	0	-	V _{CC}	V
		Tri-State Mode	0	-	5.5	
		Power Down Mode ($V_{CC} = 0 V$)	0	-	5.5	
T _A	Operating Free-Air Tempera	ature	-40	-	+125	°C
t _r , t _f	Input Transition Rise or Fall	Rate V_{I} = from 0.8 V to 2.0 V, V_{CC} = 3.0 V	0	-	10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

				T _A = -40°	C to +85°C	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$		
Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Min	Мах	Unit
VIH	High-Level Input Voltage		1.65 to 1.95	0.65 x V _{CC}	-	0.65 x V _{CC}	-	V
			2.3 to 2.7	1.7	-	1.7	-	1
			2.7 to 3.6	2.0	-	2.0	-	1
V _{IL}	Low-Level Input Voltage		1.65 to 1.95	-	0.35 x V _{CC}	_	0.35 x V _{CC}	V
			2.3 to 2.7	-	0.7	-	0.7	
			2.7 to 3.6	-	0.8	_	0.8	
V _{OH}	High–Level	$V_{I} = V_{IH} \text{ or } V_{IL}$						V
	Output Voltage	I _{OH} = -100 μA	1.65 to 3.6	$V_{CC}-0.2$	-	$V_{CC}-0.2$	-	1
		I _{OH} = -4 mA	1.65	1.2	-	1.2	-	
		I _{OH} = -8 mA	2.3	1.8	-	1.8	-	
		I _{OH} = -12 mA	2.7	2.2	-	2.2	-	
		I _{OH} = -16 mA	3.0	2.4	-	2.4	-	
		I _{OH} = -24 mA	3.0	2.2	-	2.2	-	
V _{OL}	Low-Level	$V_I = V_{IH} \text{ or } V_{IL}$						V
	Output Voltage	I _{OL} = 100 μA	1.65 to 3.6	-	0.2	-	0.2	
		I _{OL} = 4 mA	1.65	-	0.45	_	0.45	
		I _{OL} = 8 mA	2.3	-	0.6	-	0.6	
		I _{OL} = 12 mA	2.7	-	0.4	-	0.4	
		I _{OL} = 16 mA	3.0	-	0.4	-	0.4	
		I _{OL} = 24 mA	3.0	-	0.55	-	0.6	
l	Input Leakage Current	V _I = 0 to 5.5 V	3.6	-	±5.0	-	±5.0	μ/
I _{OZ}	3-State Output Leakage Current	$V_{I} = V_{IH} \text{ or } V_{IL},$ $V_{O} = 0 \text{ V to } 5.5 \text{ V}$	3.6	-	±5.0	-	±5.0	μ
I _{OFF}	Power Off Leakage Current	V _I = 5.5 V or V _O = 5.5 V	0	_	10	-	20	μ
I _{CC}	Quiescent Supply Current	$V_{I} = 5.5 V \text{ or GND}$	3.6	-	10	-	10	μ
ΔI _{CC}	Increase in I _{CC} per Input	V _{IH} = V _{CC} – 0.6 V	2.3 to 3.6	-	500	_	500	μ/

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

				$T_A = -40^\circ$	C to +85°C	T _A = -40°C	to +125°C	
Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Propagation Delay, D to O	See Figures 3 and 4	1.65 to 1.95	-	10.3	-	10.3	ns
			2.3 to 2.7	-	7.8	-	7.8	
			2.7	-	7.5	-	7.5	
			3.0 to 3.6	-	6.5	-	6.5	
t _{PZH} , t _{PZL}	Output Enable Time, OE to O	See Figures 3 and 4	1.65 to 1.95	-	13.0	-	13.0	ns
			2.3 to 2.7	-	10.0	-	10.0	
			2.7	-	9.0	-	9.0	
			3.0 to 3.6	-	8.0	-	8.0	
t _{PHZ} , t _{PLZ}	Output Disable Time, \overline{OE} to O	See Figures 3 and 4	1.65 to 1.95	-	11.0	-	11.0	ns
			2.3 to 2.7	-	8.4	-	8.4	
			2.7	-	8.0	-	8.0	
			3.0 to 3.6	-	7.0	-	7.0	
t _{OSHL} , t _{OSLH}	Output to Output Skew		1.65 to 1.95	-	-	-	-	ns
			2.3 to 2.7	-	-	-	-	
			2.7	-	-	-	-	
			3.0 to 3.6	-	1.0	-	1.0	

DYNAMIC SWITCHING CHARACTERISTICS

			T _A = +25°C				
Symbol	Parameter	Test Condition	V _{CC} (V)	Min	Тур	Max	Unit
V _{OLP}	Dynamic LOW Peak Voltage	$C_L = 50 \text{ pF}, \text{ V}_{IH} = 3.3 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	3.3	-	0.8	-	V
	(Note 4)	$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	2.5	-	0.6	-	
V _{OLV}	Dynamic LOW Valley Voltage	C_{L} = 50 pF, V_{IH} = 3.3 V, V_{IL} = 0 V	3.3	-	-0.8	-	V
	(Note 4)	$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	2.5	-	-0.6	_	

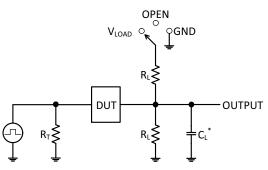
4. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Parameter Test Condition		Unit
C _{IN}	Input Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	7	pF
C _{OUT}	Output Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance (Note 5)	10 MHz, V _{CC} = 3.3 V, V _I = 0 V or V _{CC}	25	pF

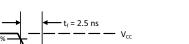
5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no-load dynamic power consumption: $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

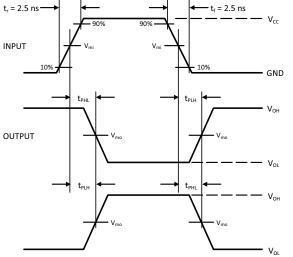
Figure 3. Test Circuits

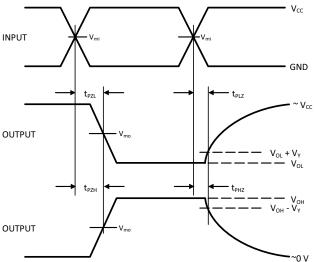


Test	Switch Position
t _{PLH} / t _{PHL}	Open
t _{PLZ} / t _{PZL}	V _{LOAD}
t _{PHZ} / t _{PZH}	GND

C_L includes probe and jig capacitance R_{T} is Z_{OUT} of pulse generator (typically 50 $\Omega)$ f = 1 MHz







V _{CC} , V	R_{L}, Ω	C _L , pF	V _{LOAD}	V _{mi} , V	V _{mo} , V	V _Y , V
1.65 to 1.95	500	30	$2 \times V_{CC}$	V _{CC} /2	V _{CC} /2	0.15
2.3 to 2.7	500	30	$2 \times V_{CC}$	V _{CC} /2	V _{CC} /2	0.15
2.7	500	50	6 V	1.5	1.5	0.3
3.0 to 3.6	500	50	6 V	1.5	1.5	0.3

Figure 4. Switching Waveforms

ORDERING INFORMATION

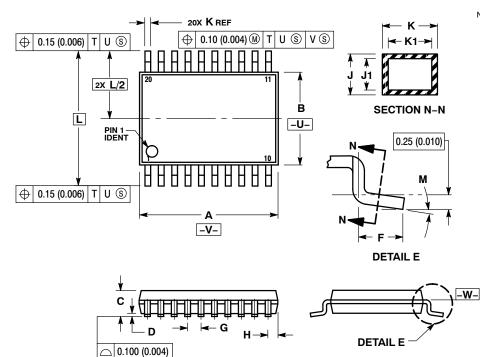
Device	Package	Shipping [†]
MC74LCX244ADTR2G	TSSOP-20 (Pb-Free)	2500 / Tape & Reel
MC74LCX244AMN2TWG (Contact ON Semiconductor)	QFN20, 2.5x3.5 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

PACKAGE DIMENSIONS

TSSOP-20 CASE 948E ISSUE D



-T- SEATING

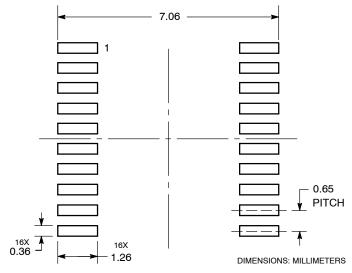
NOTES:

DIES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.

MILLIMETER. 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION. SHALL NOT EXCEED 0.25 (0.010) PER SIDE. 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION. 6. TERMINAL NUMBERS ARE SHOWN FOR

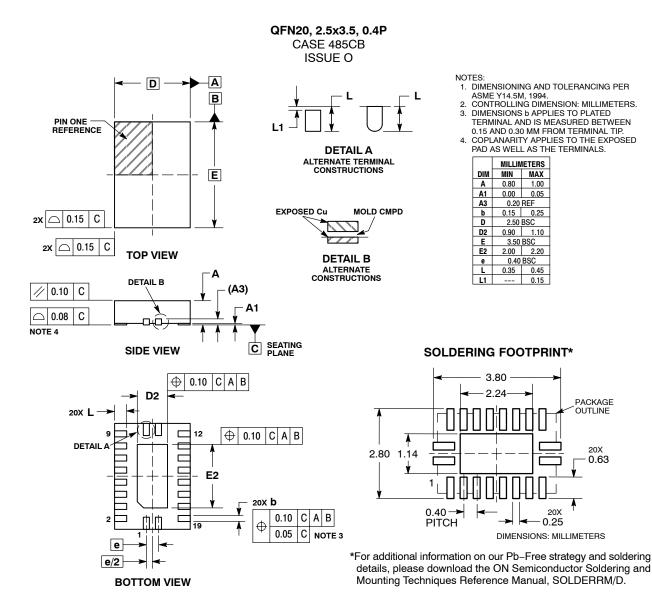
DETENTINED AT DATOM FLAME -W							
	MILLIN	IETERS	INC	HES			
DIM	MIN	MAX	MIN	MAX			
Α	6.40	6.60	0.252	0.260			
В	4.30	4.50	0.169	0.177			
С		1.20		0.047			
D	0.05	0.15	0.002	0.006			
F	0.50	0.75	0.020	0.030			
G	0.65	BSC	0.026 BSC				
Н	0.27	0.37	0.011	0.015			
J	0.09	0.20	0.004	0.008			
J1	0.09	0.16	0.004	0.006			
K	0.19	0.30	0.007	0.012			
K1	0.19	0.25	0.007	0.010			
L	6.40 BSC		0.252				
Μ	0°	8°	0°	8°			

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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LXV200-024SW 74AUP2G34FW3-7 HEF4043BP NL17SG125DFT2G NLU1GT126CMUTCG CD4041UBE 54FCT240CTDB 74HCT540N DS14C88N 070519XB NL17SZ07P5T5G 74LVC2G17FW4-7 CD4502BE 5962-8982101PA 61446R00 74LVCE1G126FZ4-7 NL17SH17P5T5G 74HCT126T14-13 74LVC2G34FW4-7 74VHC9126FT(BJ) RHRXH162244K1 74AUP1G34FW5-7 74LVC1G126FW4-7 74LVC2G126RA3-7 74LVCE1G125FZ4-7 74AUP1G126FW5-7 54FCT240TLB 74LVCE1G07FZ4-7 NLX3G16DMUTCG NLX2G06AMUTCG LE87100NQCT LE87285NQC LE87290YQC LE87290YQCT 74AUP1G125FW5-7 NLU2G16CMUTCG MC74LCX244MN2TWG NL17SG17P5T5G NLV74HC125ADR2G NLVHCT245ADTR2G NLVVHC1G126DFT2G EL5623IRZ ISL1539IRZ-T13 MC100EP17MNG MC74HCT365ADR2G MC74LCX244ADTR2G NL27WZ126US NL37WZ16US NLU1G07MUTCG NLU2G07MUTCG